

# **JWH5087AW**

# 16V/20A Synchronous Step-Down Converter

#### **DESCRIPTION**

The JWH5087AW is a monolithic buck switching regulator based on I2 architecture for fast transient response. Operating with an input range of 2.7V~16V, JWH5087AW delivers 20A of continuous output current with two integrated N-Channel MOSFETs. The internal synchronous power switches provide high efficiency without the use of an external Schottky diode. The operation frequency is set easily to 700 kHz, 800 kHz, or 1000 kHz with the MODE configuration, allowing the JWH5087AW frequency to remain constant regardless of the input and output voltages.

JWH5087AW guarantees robustness with output short protection, over-voltage protection, thermal protection and under voltage protection.

JWH5087AW is available in QFN3×4-19 package, which provides a compact solution with minimal external components.

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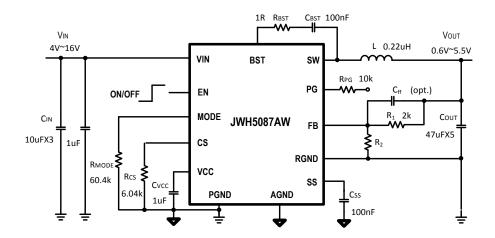
#### **FEATURES**

- 2.7V to 16V Operating Input Range with External 3.3V VCC bias
- 4V to 16V Operating Input Range with Internal Bias or External 3.3V VCC Bias
- 20A output current
- Differential Output Voltage Remote Sense
- Programmable Accurate Current Limit Level
- ±0.5% Reference Voltage over 0℃ to +70℃
   Junction Temperature Range
- FCCM Operation Mode
- Power Good Indicator
- Programmable Soft-Start Time
- Selectable Switching Frequency from 700kHz, 800kHz, and 1000kHz
- Output Discharge Function
- Non-Latch OCP, UVP, OVP, UVLO
- Thermal Protection
- Available in QFN3X4-19 Package

#### **APPLICATIONS**

- Telecom and Networking Systems
- Server, Cloud-Computing, Storage
- Base Stations
- General Purpose Point-of-Load

#### TYPICAL APPLICATION



#### **ORDER INFORMATION**

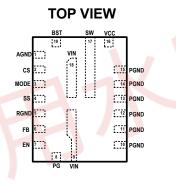
DEVICE <sup>1)</sup>	PACKAGE	TOP MARKING <sup>2)</sup>	ENVIRONMENTAL <sup>3)</sup>		
JWH5087AWQFNAS#TR	QFN3X4-19	H5087AW YW 🗆 🗆 🗆 🗆	Green		

#### Notes:



3) All JoulWatt products are packaged with Pb-free and Halogen-free materials and compliant to RoHS standards.

#### **PIN CONFIGURATION**



# ABSOLUTE MAXIMUM RATING<sup>1)</sup>

VIN Pin	0.3V to 18V
SW Pin0.3V (-5V	for 25ns) to 18V (25V for 25ns)
VIN-SW0.3V (-5V fo	r 25ns) to 18.3V (25V for 25ns)
BST-SW	0.3V to 4V (5V for 25ns)
VCC Pin	0.3V to 4V
All other Pins	0.3V to 4V
Junction Temperature 2)	150°C
Lead Temperature	260°C
Storage Temperature	65 °C to +150 °C
ESD Susceptibility (Human Body Model)	±2kV
Charged device model (CDM), per JEDEC specification JESD22-V C103	1+500V

## **RECOMMENDED OPERATING CONDITIONS<sup>3)</sup>**

Input Voltage V <sub>IN</sub>	4V to 16V
Output Voltage V <sub>OUT</sub>	
External VCC Bias V <sub>CC_EXT</sub>	Up to 3.6V
Maximum Internal VCC Output Current I <sub>VCC_MAX</sub>	150mA
Maximum Output Current I <sub>OUT_MAX</sub>	20A
Maximum Output Current Limit I <sub>OC_MAX</sub>	34A
Maximum Peak Inductor Current Limit I <sub>L_Peak</sub>	39A
Operation Junction Temperature T <sub>j</sub>	40°C to 125°C
THERMAL PERFORMANCE <sup>4)</sup>	$ heta_{\scriptscriptstyle J\!B}$ $^{5j}$ $ heta_{\scriptscriptstyle J\!c\_T\!O\!P}$ $^{5j}$
QFN3X4-19	9923°C/W

#### Note:

- 1) Exceeding these ratings may damage the device. These stress ratings do not imply function operation of the device at any other conditions beyond those indicated under RECOMMENDED OPERATING CONDITIONS.
- 2) The JWH5087AW includes thermal protection that is intended to protect the device in overload conditions. Continuous operation over the specified absolute maximum operating junction temperature may damage the device.
- 3) The device is not guaranteed to function outside of its operating conditions.
- 4) Measured on JESD51-7, 4-layer PCB.
- 5)  $\theta_{B}$  Thermal resistance from junction to board around PGND pin soldering point.
  - $\theta_{ke,rop}$  Thermal resistance from junction to top of package.

### **ELECTRICAL CHARACTERISTICS**

$V_{IN}=12V$ , $T_{J}=-40~C\sim125~C$ , Unless otherwise stated.									
Item	Symbol	Min.	Тур.	Max.	Unit				
V Haday Voltaga Lagly aut Thysobold	V <sub>IN_HTH</sub>	V <sub>IN</sub> rising, V <sub>CC</sub> =3.3V	2.1	2.4	2.7	V			
V <sub>IN</sub> Under Voltage Lock-out Threshold	V <sub>IN_LTH</sub>	V <sub>IN</sub> falling, V <sub>CC</sub> =3.3V	1.55	1.85	2.15	V			
Shutdown Current	I <sub>SD</sub>	V <sub>EN</sub> =0		0.5	5	μA			
Supply Current	ΙQ	V <sub>EN</sub> =2V, V <sub>FB</sub> =0.7V		550	800	μΑ			
Enable Input Rising Threshold	V <sub>EN_HTH</sub>		1.17	1.22	1.27	V			
Enable Hysteresis	V <sub>EN_TH_HYS</sub>			200		mV			
Enable Input Current	I <sub>EN</sub>	V <sub>EN</sub> =2V		0		μΑ			
Foodback Voltage	V <sub>REF</sub>	T <sub>J</sub> =-40℃ to 125℃	594	600	606	mV			
Feedback Voltage	VREF	T <sub>J</sub> = 0°C to 70°C	597	600	603	mV			
Feedback Current	I <sub>FB</sub>	V <sub>FB</sub> =0.6V		10	100	nA			
Top Switch Resistance	R <sub>DS(ON)T</sub>			8.6	13.5	mΩ			
Bottom Switch Resistance	R <sub>DS(ON)B</sub>			2.5	4.5	mΩ			
Top Switch Leakage Current	ILEAK_TOP	V <sub>IN</sub> =16V, V <sub>SW</sub> =0V			10	μA			
Bottom Switch Leakage Current	ILEAK_BOT	V <sub>IN</sub> =16V, V <sub>SW</sub> =16V			10	μΑ			
Current Limit Threshold	VLIM		1.15	1.2	1.25	V			
ICS to IOUT Ratio	I <sub>CS</sub> /I <sub>OUT</sub>	R <sub>CS</sub> =6K	8	9	11	μA/A			
Bottom Switch Negative Current Limit	ILIM_NEG		-21	-16	-12	Α			
Minimum On Time <sup>6)</sup>	Ton_min				50	ns			
Minimum Off Time <sup>6)</sup>	Toff_MIN			100	180	ns			
	Fsw	MODE=GND	560	660	760	kHz			
Switching Frequency		MODE=30.1K	640	750	860	kHz			
		MODE=60.4K	860	970	1080	kHz			
Discharge FET Ron	R <sub>DIS</sub>			110	200	Ω			
Soft-Start Charge Current	Iss_char	V <sub>SS</sub> =0V		42		μA			
Soft-Start Pull Down Current	Iss_dischar	V <sub>SS</sub> =1V	0.4	0.55	0.7	mA			
Soft-Start Time <sup>6)</sup>	T <sub>SS</sub>	C <sub>SS</sub> =1nF	0.5	1	1.5	ms			
	V <sub>CC_НТН</sub>	V <sub>CC</sub> rising	2.65	2.8	2.95	V			
VCC Under-voltage Lockout Threshold	V <sub>CC_LTH</sub>	Vcc falling	2.35	2.5	2.65	V			
VCC Regulator	V <sub>CC</sub>		3.1	3.2	3.35	V			
VCC Load Regulation		I <sub>CC</sub> =100mA		0.5		%			
B 0 1151 - 1 11	20	V <sub>FB</sub> from low to high	89.5%	92.5%	95.5%	V <sub>REF</sub>			
Power Good High Threshold	PG_ <sub>HTH</sub>	V <sub>FB</sub> from high to low	102%	105%	108%	V <sub>REF</sub>			
		V <sub>FB</sub> from low to high	113%	117%	121%	V <sub>REF</sub>			
Power Good Low Threshold	PG_LTH	V <sub>FB</sub> from high to low	77%	80%	83%	V <sub>REF</sub>			
Power Good Delay Time	PG_DLY	V <sub>PG</sub> from low to high	0.7	1.1	1.5	ms			

$V_{IN}$ =12V, $T_J$ =-40 $C$ ~125 $C$ , Unless otherwise stated.								
Item	Symbol	Conditions	Min.	Тур.	Max.	Unit		
Power Good Sink Current	I <sub>PG</sub>	V <sub>PG</sub> =0.5V	3			mA		
Power Good Leakage Current	ILEAK_PG	V <sub>PG</sub> =3.3V		3.5	5	μA		
Power Cood Low level Output Voltage	V <sub>OL_100</sub>	V <sub>IN</sub> =0V, Pull PG up to 3.3V through a 100kΩ resistor		520	800	mV		
Power Good Low-level Output Voltage	Vol_10	$V_{IN}$ =0V, Pull PG up to 3.3V through a $10k\Omega$ resistor		620	900	mV		
Output Over-voltage Threshold		V <sub>FB</sub> Rising	113%	117%	121%	$V_{REF}$		
Output Under-voltage Threshold		V <sub>FB</sub> Falling	77%	80%	83%	$V_{REF}$		
Output UVP Delay	T <sub>DLY_UVP</sub>			1.7		μs		
UVP/OCP Hiccup OFF Time	THICCUP_OFF			12		ms		
Thermal Shutdown <sup>6)</sup>	T <sub>TSD</sub>			160		°C		
Thermal Shutdown Hysteresis <sup>6)</sup>	T <sub>TSD_HYST</sub>			30		°C		
Power On Delay Time	T <sub>DLY_POWERON</sub>			95		μs		

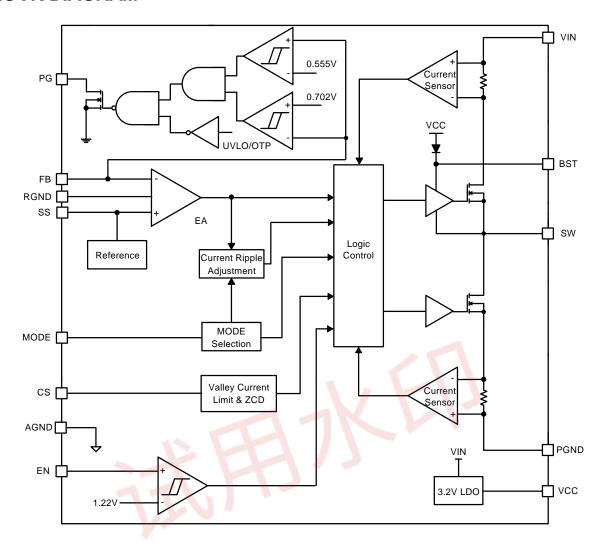
#### Note:

6) Guaranteed by design.

### **PIN DESCRIPTION**

Pin	Name	Description
1	AGND	Analog ground pin. Select AGND as the control circuit reference point.
2	CS	Current limit. Connect a resistor to AGND to set the current limit trip point.
3	MODE	Frequency selection. Program MODE to select the operating switching frequency.
4	SS	Soft-start time setting pin. The soft-start time is determined by the capacitance between SS pin and AGND.
5	RGND	Differential remote sense negative input. Connect this pin directly to the negative side of the voltage sense point. Short to GND if remote sense is not used.
6	FB	Feedback (Differential remote sense positive input). An external resistor divider from the output to RGND (tapped to FB) sets the output voltage. It is recommended to place the resistor divider as close to FB as possible. Vias should be avoided on the FB traces.
7	EN	Enable control pin. Pull this pin high to turn on the regulator. Do not leave this pin floating.
8	PG	Power good monitor output. Open drain output when the output voltage is within 92.5% to 117% of internal reference voltage.
9, 18	VIN	Input voltage pin. VIN supplies power to the IC. Connect a 2.7V to 16V supply to VIN and bypass VIN to GND with a suitably large capacitor to eliminate noise on the input to the IC.
10-15	GND	Power ground pin
16	VCC	Internal 3.2V LDO Output. Power supply for internal analog circuits and driving circuit.  Decouple this pin to ground with a minimum 1uF ceramic capacitor.
17	SW	SW is the switching node that supplies power to the output. Connect the output LC filter from SW to the output load.
19	BST	Connect a 0.1uF capacitor between BST and SW pin to supply current for the top switch driver. A BOOT resistor with a value of at least $1\Omega$ is recommended to place in series with the BOOT capacitor to reduce the voltage spike at SW.

# **BLOCK DIAGRAM**

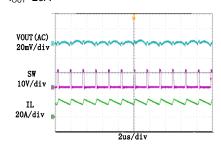


#### TYPICAL PERFORMANCE CHARACTERISTICS

 $V_{IN}$  = 12V,  $V_{OUT}$  = 1.2V, L = 0.22 $\mu$ H,  $C_{OUT}$  = 47 $\mu$ F $\times$ 5,  $F_{SW}$  = 700kHz,  $R_{BOOT}$ =1 $\Omega$ ,  $T_A$  = +25°C, unless otherwise noted.

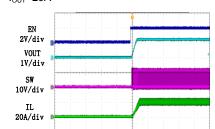
#### **Steady State Test**

 $V_{IN}$ =12V,  $V_{OUT}$ =1.2V  $I_{OUT}$ =20A



#### Startup through Enable

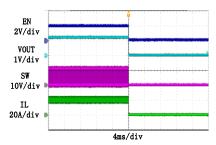
 $V_{IN}$ =12V,  $V_{OUT}$ =1.2V  $I_{OUT}$ =20A



#### Shutdown through Enable

 $V_{IN}$ =12V,  $V_{OUT}$ =1.2V

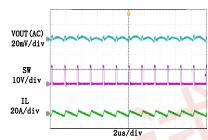
I<sub>OUT</sub>=20A



#### **Steady State Test**

 $V_{IN}$ =12V,  $V_{OUT}$ =1.2V

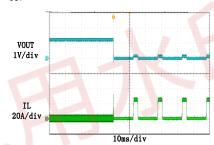
I<sub>OUT</sub>=0A



#### **Short Circuit Protection**

 $V_{IN}$ =12V,  $V_{OUT}$ =1.2V

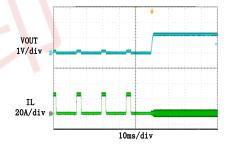
 $I_{OUT}$ =0A $\rightarrow$ Short



#### **Short Circuit Recovery**

V<sub>IN</sub>=12V, V<sub>OUT</sub>=1.2V

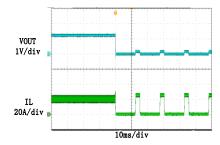
I<sub>OUT</sub>=Short→0A



#### **Short Circuit Protection**

V<sub>IN</sub>=12V, V<sub>OUT</sub>=1.2V

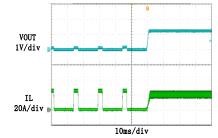
I<sub>OUT</sub>=20A→Short



#### **Short Circuit Recovery**

 $V_{IN}$ =12V,  $V_{OUT}$ =1.2V

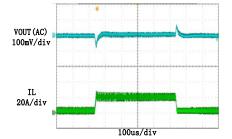
I<sub>OUT</sub>=Short→20A



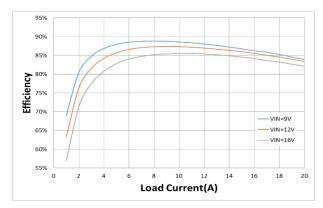
#### **Load Transient**

V<sub>IN</sub>=12V, V<sub>OUT</sub>=1.2V

I<sub>OUT</sub>=2A~20A



### TYPICAL PERFORMANCE CHARACTERISTICS



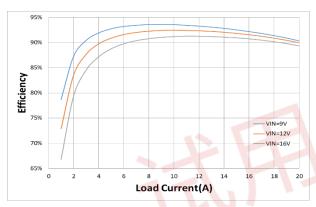
95% 90% 85% 85% 65% 65% 60% 0 2 4 6 8 10 12 14 16 18 20 Load Current(A)

Efficiency vs. Load Current

 $(V_{OUT}=1.2V, L=0.22uH, F_{SW}=700kHz)$ 

**Efficiency vs. Load Current** 

(V<sub>OUT</sub>=1.8V, L=0.22uH, F<sub>SW</sub>=1MHz)



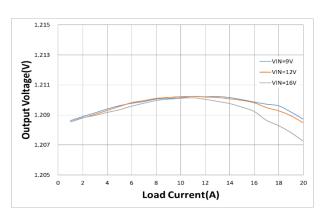


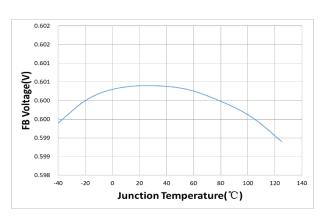
Efficiency vs. Load Current

(V<sub>OUT</sub>=3.3V, L=0.22uH, F<sub>SW</sub>=1MHz)

Frequency vs. Load Current

 $(V_{IN}=12V, V_{OUT}=1.8V, L=0.22\mu H)$ 





**Load Regulation** 

 $(V_{OUT}=1.2V, L=0.22uH, F_{SW}=700kHz)$ 

FB Voltage Regulaion vs. Junction Temperature

#### **FUNCTIONAL DESCRIPTION**

JWH5087AW is a synchronous step-down regulator based on I2 control architecture. It regulates input voltages from 2.7V to 16V down to as low as 0.6V output voltage, and is capable of supplying up to 20A of load current.

#### **Power Switch**

N-Channel MOSFET switches are integrated on the JWH5087AW to down convert the input voltage to the regulated output voltage. Since the top MOSFET needs a gate voltage greater than the input voltage, a boost capacitor connected between BST and SW pins is required to drive the gate of the top switch. The boost capacitor is charged by the internal/external rail when SW is low.

#### **Frequency Selection**

JWH5087AW operates in forced continuous conduction mode (FCCM), and the switching frequency is fairly constant; hence the output ripple keeps almost the same throughout the whole load range.

JWH5087AW has three options for switching frequency selection. Selecting the switching frequency is done by choosing the resistance value of the resistor connected between MODE and AGND (See Table 1).

Table 1 --- Frequency selection

MODE	Switching Frequency <sup>7)</sup>
GND	700kHz
30.1kΩ(±20%) to GND	800kHz
60.4kΩ(±20%) to GND	1000kHz

#### Note:

**7)** Refer to ELECTRICAL CHARACTERISTICS for more accurate switching frequency data.

#### **Shut-Down Mode**

The JWH5087AW shuts down when voltage at EN pin is below 0.3V. The entire regulator is off and the supply current consumed by the JWH5087AW drops below 5uA.

#### **VIN Under-Voltage Protection**

In addition to the enable function, the JWH5087AW provides an Under Voltage Lockout (UVLO) function that monitors the input voltage. To prevent operation without fully-enhanced internal MOSFET switches, this function inhibits switching when input voltage drops below the UVLO-falling threshold. The IC resumes switching when input voltage exceeds the UVLO-rising threshold.

# Enable and Adjustable UVLO Protection

The JWH5087AW is enabled when the VIN pin voltage rises above 2.4V and the EN pin voltage exceeds the enable threshold of 1.22V. The JWH5087AW is disabled when the VIN pin voltage falls below 1.85V or when the EN pin voltage is below 1.02V. Do not leave this pin floating.

If an application requires a higher  $V_{IN}$  undervoltage lockout (UVLO) threshold, use a resistive divider connected between VIN and ground with the central tap connected to EN to adjust the input voltage UVLO (Shown in Figure 1). So that when  $V_{IN}$  rises to the pre-set value,  $V_{EN}$  rises above 1.22V to enable the device and when  $V_{IN}$  drops below the pre-set value,  $V_{EN}$  drops below 1.02V to trigger input under voltage lockout protection.

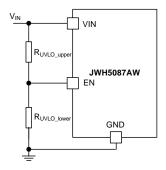


Figure. 1 Adjustable UVLO

The input voltage UVLO threshold ( $V_{UVLO}$ ) and hysteresis ( $V_{UVLO\_HYS}$ ) can be calculated by the following equation.

$$v_{UVLO} := \frac{\textit{R}_{UVLO\_upper} + \textit{R}_{UVLO\_lower}}{\textit{R}_{UVLO} \text{ lower}} \cdot v_{EN\_TH}$$

$$V_{\text{UVLO\_HYS}} := \frac{R_{\text{UVLO\_upper}} + R_{\text{UVLO\_lower}}}{R_{\text{UVLO}\ lower}} \cdot V_{\text{EN\_HYS}}$$

#### where

 $V_{EN\_TH}$  is enable shutdown threshold (1.22V typ.);

V<sub>EN\_HYS</sub> is enable shutdown hysteresis (200mV typ.).

#### **Soft Start**

Soft-start is designed in JWH5087AW to prevent the converter output voltage from overshooting during startup and short-circuit recovery. An internal current source ( $I_{SS}$ ) of 42uA is designed to charge the external soft-start capacitor ( $C_{SS}$ ) and generates a soft-start (SS) voltage ramping up from 0V to 1.5V. When it is less than internal reference voltage ( $V_{REF}$ , typ. 0.6V), SS voltage overrides  $V_{REF}$  and the error amplifier uses SS voltage as the reference. When SS exceeds  $V_{REF}$ ,  $V_{REF}$  regains control.

The soft start time (10% to 90%)  $T_{SS}$  can be calculated by the following equation.

$$T_{SS}(ms) := \frac{C_{SS}(nF) \cdot V_{REF}(V) \cdot 0.8}{I_{SS}(\mu A)}$$

where  $C_{SS}$  is the soft-start capacitance connected between SS pin and AGND pin.

The JWH5087AW has a configured external soft start time and a constant internal soft start time, it will follow the slower one between them. Therefore, the minimum soft start time is about 1ms even a smaller capacitor is used. The soft start will not be ready until both the internal and external SS voltage exceeds 0.85V.

At power up, the soft start pin is discharged before MOSFETs switching to ensure a proper power up. Also, during normal operation, the JWH5087AW will stop switching and the soft-start pin will be discharged, when the  $V_{\text{IN}}$  UVLO is exceeded, EN pin pulled below 1.02V, or a thermal shutdown event occurs.

# Current Sense and Over-Current Protection (OCP)

The JWH5087AW features an on-die current sense and a programmable positive current limit threshold.

The cycle-by-cycle current limit is activated when the JWH5087AW is enabled. The SW valley current limit is proportional to I<sub>CS</sub> current, which is set by a resistor (R<sub>CS</sub>) from CS to AGND.

The following equation calculates the current limit threshold setting from  $R_{\text{CS}}$ :

$$R_{CS}\left(\Omega\right) := \frac{v_{OCP}}{G_{CS} \cdot \left[I_{LIM} - \frac{\left(V_{IN} - V_{OUT}\right) \cdot V_{OUT}}{V_{IN}} \cdot \frac{1}{2 \cdot L \cdot f_{SW}}\right]}$$

where

V<sub>OCP</sub>=1.2V,

 $G_{CS} = 9 \mu A/A$ , and

 $I_{LIM}$  = the desired output current limit.

The OCP HICCUP is active 3ms after the JWH5087AW is enabled, Once OCP HICCUP is active, if the JWH5087AW detects over-current condition for consecutive 31 cycles, or if the FB drops below under-voltage protection (UVP) threshold, it enters HICCUP mode. In HICCUP mode, the JWH5087AW latches off the high side MOSFET immediately, and latches off low side

MOSFET after ZCD is detected. Meanwhile, the SS capacitor is also discharged. After about 12ms, the JWH5087AW will try to soft start automatically. If the over-current condition still holds after 3ms of running, the JWH5087AW repeats this operation cycle until the over-current condition disappears, and the output voltage rises smoothly back to the regulation level.

#### **Negative Inductor Current limit**

When the low side MOSFET detects a -16A current, the part turns off the low side MOSFET to limit the negative current.

#### **Pre-Bias Start-Up**

The JWH5087AW has been designed for a monotonic start-up into pre-biased loads. If the output is pre-biased to a certain voltage during start-up, the IC disables switching for both the high-side and low-side MOSFETs until the voltage on the SS capacitor exceeds the sensed output voltage at FB. Before SS voltage reaches pre-biased FB level, if the BST voltage (from BST to SW) is lower than 1.8V, the low-side MOSFET is turned on to allow the BST voltage to be charged through VCC. The low-side MOSFET is turned on for very narrow pulses, so the drop in pre-biased level is negligible.

#### **Output Voltage Discharge**

When the JWH5087AW is disabled through EN, it enables the output voltage discharge mode. This causes both the high side MOSFET and the low side MOSFET to latch off. A discharge FET connected between SW and PGND is turned on to discharge the output voltage. The typical switch on resistance of this FET is about  $110\Omega$ . Once the FB voltage drops below 10% V<sub>REF</sub>, the discharge FET is turned off.

#### **Output Over-voltage Protection**

The JWH5087AW monitors the output voltage by connecting FB to the tap of the output voltage feedback resistor divider to detect an overvoltage condition. This provides autorecovery OVP mode.

If the FB voltage is between 105% and 117% of REF voltage, the low side MOSFET remains on until it hits the low-side negative current limit (NOCP). Once it hits NOCP, the low side MOSFET is turned off and the high side MOSFET is turned on until the negative current reaches to zero. The JWH5087AW keeps this operation to try to bring down the output voltage.

If the FB voltage furtherly exceeds 117% of the REF voltage, it enters OVP mode. The high side MOSFET is turned off and the low side MOSFET remains on until it hits NOCP. Once it hits NOCP, the power MOSFETs stop switching. The power MOSFETs would not restart switching until the FB voltage drops below 105% of REF voltage. PGOOD goes low until the FB voltage drops below 105% of REF voltage.

#### **Power Good**

The JWH5087AW has power-good (PG) output. The PG pin is the open drain of a MOSFET. Connect to VCC or another voltage source through a resistor. After applying the input voltage, the power MOSFETs start switching, and PG is pulled to GND before soft start is ready. After the FB voltage reaches 92.5% of the REF voltage and soft start is ready, PG is pulled high after a 1.1ms delay.

When the FB voltage drops to 80% of the REF voltage, PG is pulled low within 1.7us deglitch time. When the FB voltage rises above 92.5% of the REF voltage, PG is pulled high again after a 1.1ms delay time.

When the FB voltage exceeds 117% of the REF voltage, PG is pulled low within 1.7us deglitch time. When the FB voltage drops to 105% of the REF voltage, PG is pulled high again with 1.1ms deglitch time.

Once EN UVLO or OTP is triggered, PG is pulled

low within 1.7us deglitch time even FB voltage is still in threshold range.

If the input supply fails to power the JWH5087AW, PG is clamped low even though PG is tied to an external DC source through a pull-up resistor.

#### **Thermal Protection**

When the temperature of the JWH5087AW rises above 160°C, it is forced into thermal shut-down and SS capacitor is discharged.

Only when core temperature drops below 130°C can the regulator become active again.



#### APPLICATION INFORMATION

#### **Output Voltage Set**

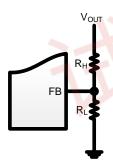
The output voltage is determined by the resistor divider connected at the FB pin, and the voltage ratio is:

$$V_{FB} = V_{OUT} * \frac{R_L}{R_H + R_L}$$

where  $V_{\text{FB}}$  is the feedback voltage and  $V_{\text{OUT}}$  is the output voltage.

To improve efficiency at very light load, using larger value resistors is preferred. However, using too high of resistance causes the circuit to be more susceptible to noise, and voltage errors from the  $V_{FB}$  input current will be more noticeable. If  $R_{H}$  is determined, such as  $2k\Omega,$  and then  $R_{L}$  can be calculated by:

$$R_L = \frac{R_H}{\frac{V_{OUT}}{0.6} - 1}$$



#### **Input Capacitor**

The input capacitor is used to supply the AC input current to the step-down converter and maintain the DC input voltage. The capacitors must have a ripple current rating that exceeds the converter's maximum input ripple current. The RMS ripple current through the input capacitor can be calculated by:

$$I_{CIN} = I_{OUT} * \sqrt{\frac{V_{OUT}}{V_{IN}} * \left(1 - \frac{V_{OUT}}{V_{IN}}\right)}$$

where  $I_{OUT}$  is the load current,  $V_{OUT}$  is the output voltage,  $V_{IN}$  is the input voltage.

Thus, the input capacitor can be calculated by

the following equation when the input ripple voltage is determined.

$$C_{IN} = \frac{I_{OUT}}{F_{SW} * \Delta V_{IN}} * \frac{V_{OUT}}{V_{IN}} * \left(1 - \frac{V_{OUT}}{V_{IN}}\right)$$

where  $C_{IN}$  is the input capacitance value,  $F_{SW}$  is the switching frequency,  $\Delta V_{IN}$  is the input ripple voltage.

The input capacitor can be electrolytic, tantalum or ceramic. To minimizing the potential noise, a small X5R or X7R ceramic capacitor, e.g.,  $0.1\mu F$ , should be placed as close to the IC as possible when using electrolytic capacitors.  $3x10\mu F/25V$  ceramic capacitors are recommended in typical application.

#### **Output Capacitor**

The output capacitor is required to maintain the DC output voltage, and the capacitance value determines the output ripple voltage. The output voltage ripple can be calculated by:

$$\Delta V_{OUT} = \frac{V_{OUT}}{F_{SW}*L}*\left(1 - \frac{V_{OUT}}{V_{IN}}\right)*\left(R_{ESR} + \frac{1}{8*F_{SW}*C_{OUT}}\right)$$

where  $C_{\text{OUT}}$  is the output capacitance value and  $R_{\text{ESR}}$  is the equivalent series resistance value of the output capacitor.

The output capacitor can be low ESR electrolytic, tantalum or ceramic, which lower ESR capacitors get lower output ripple voltage.

The output capacitors also affect the system stability and transient response, and at least 5x47µF ceramic capacitors are recommended in typical application.

#### Inductor

The inductor is used to supply constant current to the output load, and the value determines the ripple current which affect the efficiency and the output voltage ripple. The ripple current is typically allowed to be 40% of the maximum

switch current limit, thus the inductance value can be calculated by:

$$L = \frac{V_{OUT}}{F_{SW}*\Delta I_L}*\left(1 - \frac{V_{OUT}}{V_{IN}}\right)$$

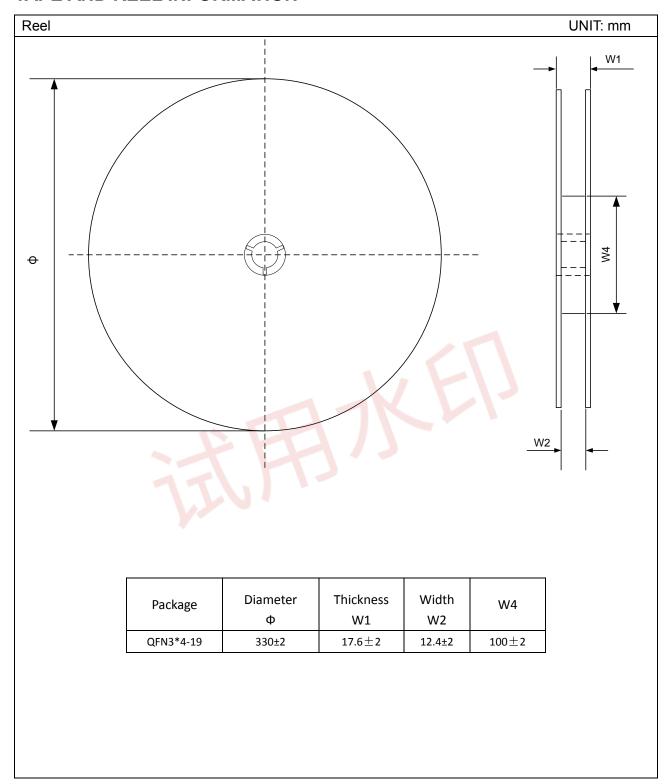
where  $V_{IN}$  is the input voltage,  $V_{OUT}$  is the output voltage,  $F_{SW}$  is the switching frequency, and  $\Delta I_L$  is the peak-to-peak inductor ripple current.

#### **External Bootstrap Capacitor**

The bootstrap capacitor is required to supply voltage to the top switch driver. A 0.1µF low ESR ceramic capacitor is recommended to connected to the BST pin and SW pin.

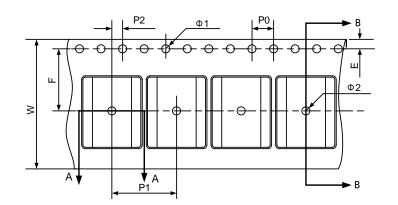


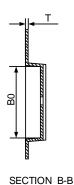
### TAPE AND REEL INFORMATION

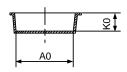


**JoulWatt** JWH5087AW

Carrier Tape UNIT: mm







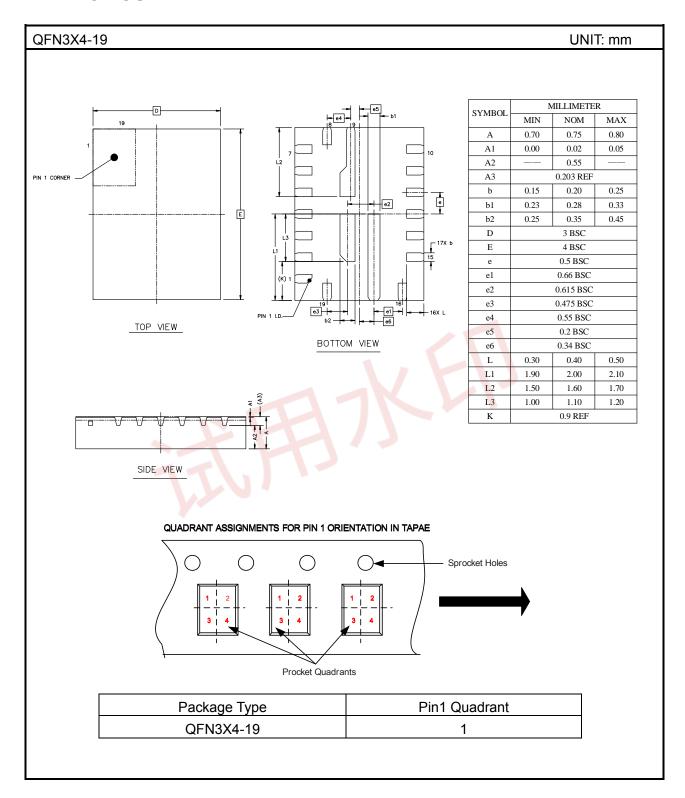
SECTION A-A

- Note:
  1) The carrier type is black, and colorless transparent.
  2) Carrier camber is within 1mm in 100mm.
  3) 10 pocket hole pitch cumulative tolerance:±0.20.

  - 4) All dimensions are in mm.

Doekogo	Tape dimensions (mm)											
Package	P0	P2	P1	A0	В0	W	Т	КО	Ф1	Ф2	E	F
QFN3*4-19	4.0±0.1	2.0±0.1	8.0±0.1	3.30±0.2	4.30±0.2	12±0.3	0.25±0.1	1.1±0.15	1.5±0.10	1.55±0.1	1.75±0.1	5.50±0.10

#### **PACKAGE OUTLINE**



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